# NSN 5961-01-532-7908

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# Inclosure Material:

Metal

# Overall Length:

Between 0.740 inches and 1.010 inches

# Terminal Length:

Between 0.500 inches and 0.750 inches

## **Overall Diameter:**

Between 0.335 inches and 0.370 inches

# Internal Configuration:

Junction contact

# Joint Electronic Device Engineering Council/jedec/case Outline Designation:

# To-205

Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

# Pnp

Mounting Method:

Terminal

# Terminal Circle Diameter:

Between 0.016 inches and 0.021 inches

# Features Provided:

Burn in and hermetically sealed case

# Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 5.5 emitter to base voltage, static, collector open

### **Current Rating Per Characteristic:**

2.00 amperes source cutoff current

### **Power Rating Per Characteristic:**

1.0 watts small-signal input power, common-emitter outside diameter

### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

### **Special Features:**

Used in high-speed power-switching applications

### **Terminal Type And Quantity:**

3 uninsulated wire lead

### Shelf Life:

N/a

### Unit Of Measure:

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#### Demilitarization:

No

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